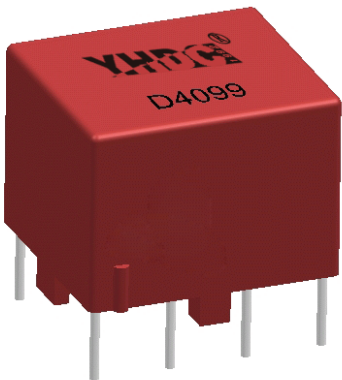


characteristics:

It is used to drive IGBT,MOS pipe and transmit high-frequency signal isolation.

Technical indicators:

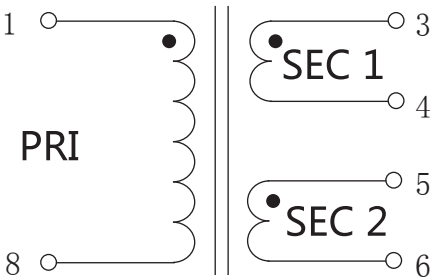
- Installation method: PCB
- Flame resistance: UL94-V0
- Operating temperature: -40℃~+85℃
- Storage temperature: : -40℃~+90℃
- Frequency range: 30KHz~200KHz
- Dielectric strength: 3.1KV 50Hz 1min



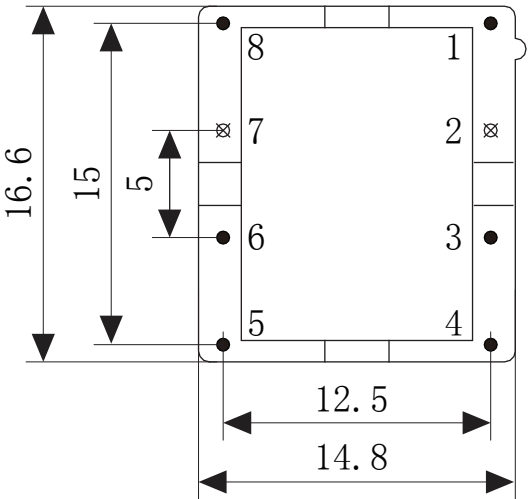
Electrical parameters:

Vout microsecond integral	150	μvs
Pulse width (D=1:2)	7.5	μs
Ratio	2:1:1	
Input amplitude	20	V
Output amplitude	8.8	V
Load impedance	100	Ω
Leading edge time	≤1	μs
Main circuit operating voltage	380	V
Weight		g

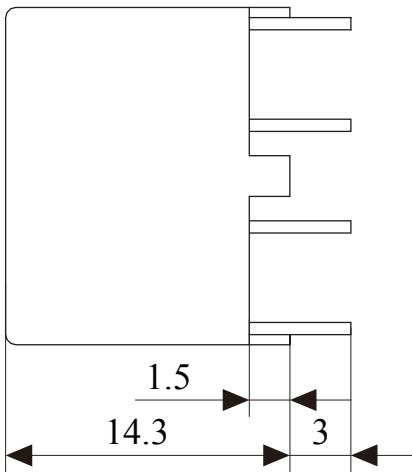
Connection diagram:



Dimensions (in mm) :



Bottom View



Side View